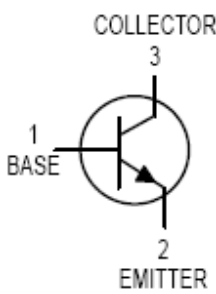
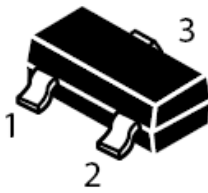


NPN General Purpose Transistor		
<p>FEATURES</p> <ul style="list-style-type: none"> • Ideally suited for automatic insertion • For Switching and AF Amplifier Applications <p>MECHANICAL DATA</p> <ul style="list-style-type: none"> • Case: SOT-23 Plastic • Case material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl) • Lead Free in RoHS 2002/95/EC Compliant 		

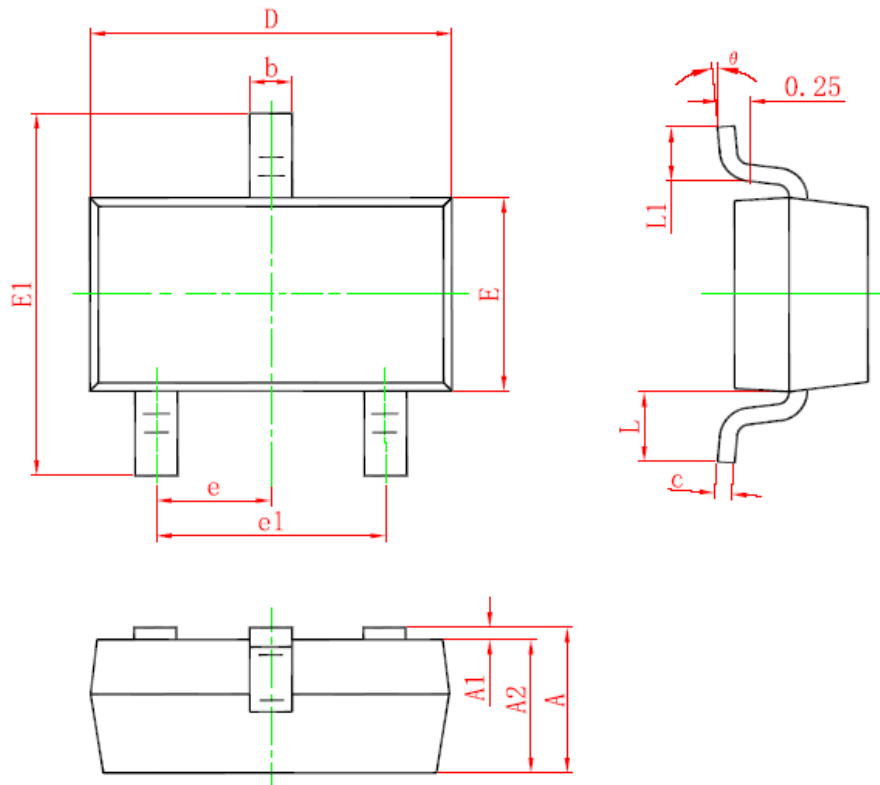
Maximum Ratings @ T_A = 25°C

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current -Continuous	I _C	100	mA
Collector Power Dissipation	P _C	200	mW
Junction Temperature	T _J	150	°C
Storage Temperature Range	T _{STG}	-65~+150	°C

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Test Condition	Symbol	Min.	Typ.	Max.	Unit
Collector-base breakdown voltage	I _C =10μA, I _E =0	V _{CBO}	50			V
Collector-emitter breakdown voltage	I _C =10mA, I _B =0	V _{CEO}	45			V
Emitter-base breakdown voltage	I _E =10μA, I _C =0	V _{EBO}	6			V
Collector-base cut-off current	V _{CB} =50V, I _E =0	I _{CBO}			0.1	uA
Collector-emitter cut-off current	V _{CE} =45V, I _B =0	I _{CEO}			0.1	uA
Emitter-base cut-off current	V _{EB} =5V, I _C =0	I _{EBO}			0.1	uA
DC current gain	V _{CE} =5V, I _C =2mA	A	110		220	
		B	200		450	
		C	420		800	
Collector-emitter saturation voltage	I _C =100mA, I _B =5mA	V _{CE(sat)}			0.5	V
Base-emitter saturation voltage	I _C =100mA, I _B =5mA	V _{BE(sat)}			1.1	V
Transition frequency	V _{CE} =5V, I _C =10mA, f=100MHz	f _T	100			MHz
Collector output capacitance	V _{CB} =10V, f=1MHz	C _{ob}			4.5	pF

SOT-23 Outline Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	6°

Device Marking :

Device P/N	Classification of h_{FE}	Marking code
BC847A	110-220	1E
BC847B	200-450	1F
BC847C	420-800	1G

Electrical characteristic curves

Fig.1 DC Current Gain

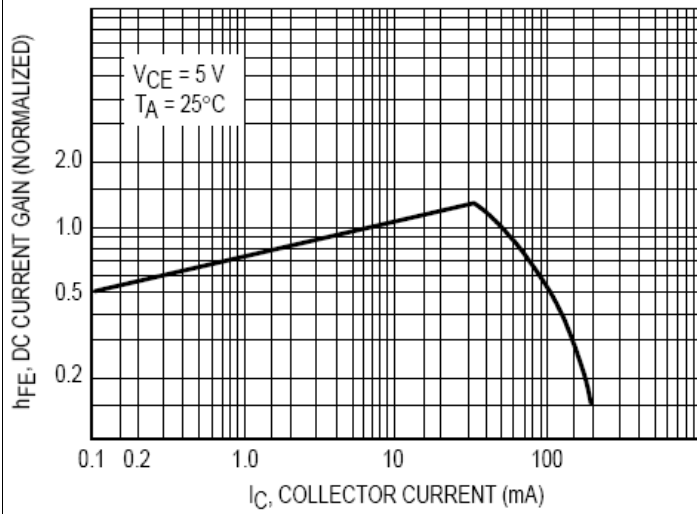


Fig.2 "Saturation" and "On" Voltages

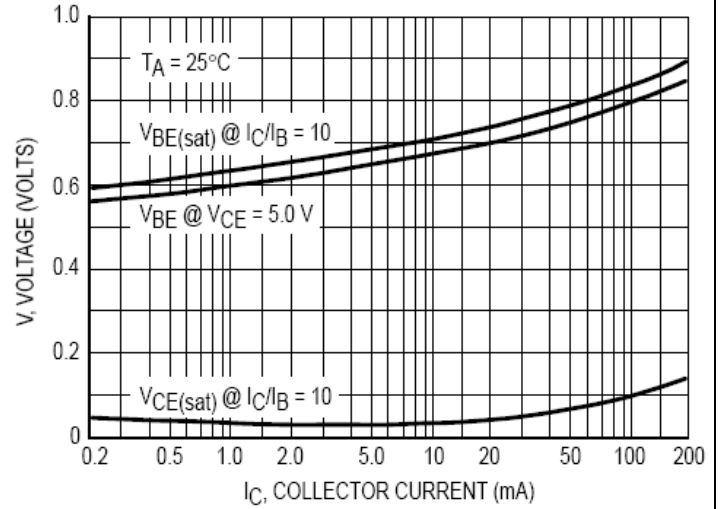


Fig.3 Collector Saturation Region

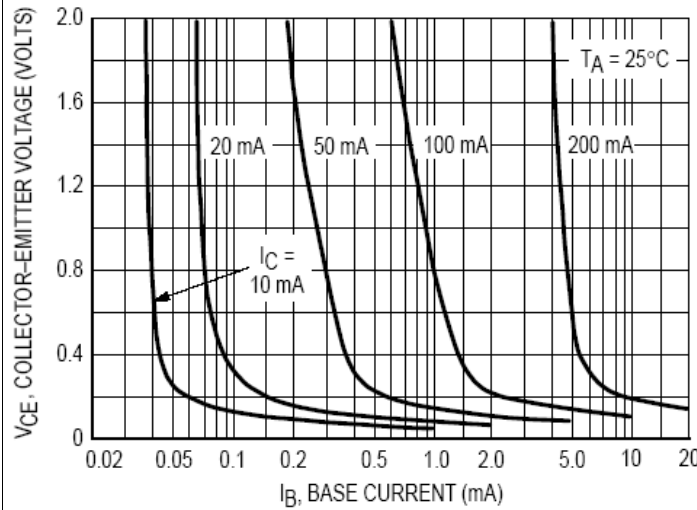


Fig.4 Base-Emitter Temperature Coefficient

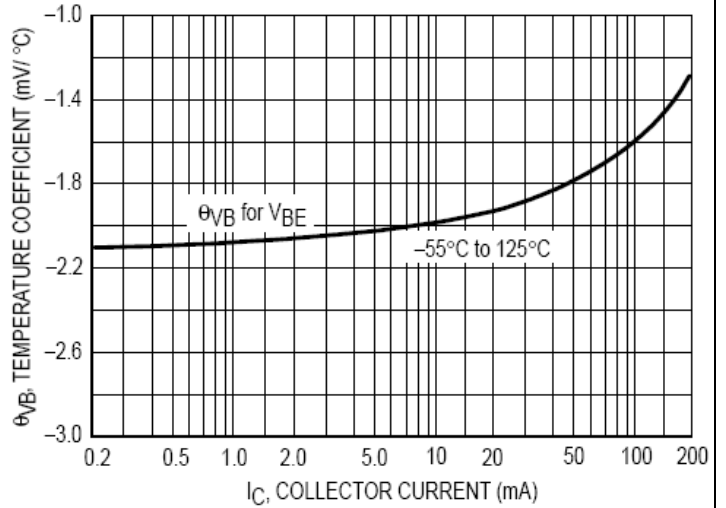


Fig.5 Capacitances

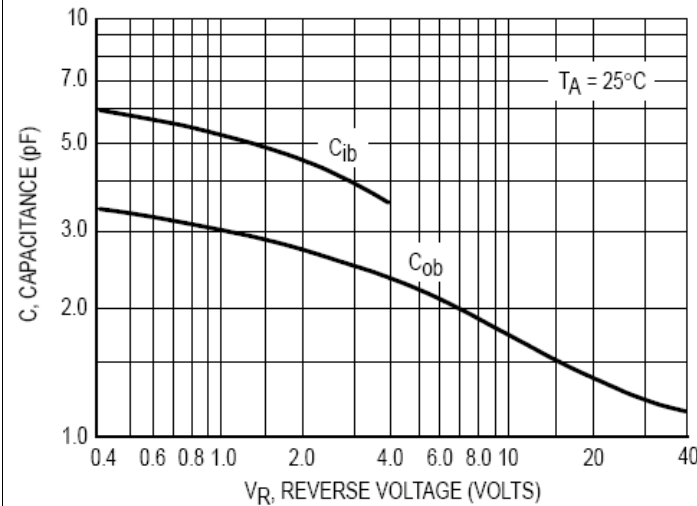
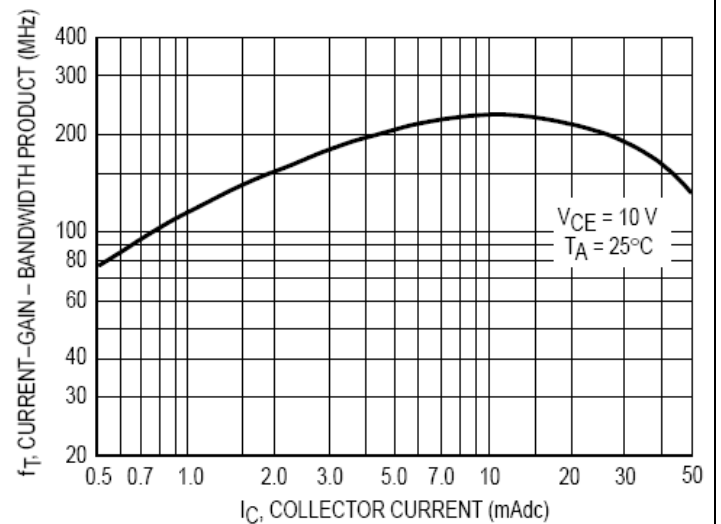


Fig.6 Current-Gain - Bandwidth Product



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